Unitized Semiconductor Devices - Page 1 of 1



dc all transistor and 6.0 emitter to base voltage, dc all

View Online at https://aerobasegroup.com/nsn/5961-00-055-9576
Inclosure Material:
Metal
Overall Length:
0.260 inches
Overall Diameter:
0.370 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-77
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
45.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage,
transistor
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
300.0 milliwatts small-signal input power, common-collector absolute all transistor
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0